

CLAIMS

1. A method of manufacturing a field electron emission cathode having at least one cathode electrode which comprises a field emitting layer (302) between first and second conducting layers (301, 303), and at least one gate electrode which overlies said cathode electrode and comprises an insulating layer (304) and a third conducting layer (305), characterised in that said method comprises the steps of:
- a. depositing on an insulating substrate (300) to form by low resolution means, a sequence of said first conducting layer (301), field emitting layer (302) and second conducting layer (303) to form said at least one cathode electrode;
 - b. depositing on said cathode electrode to form by low resolution means, a sequence of said insulating layer (304) and third conducting layer (305), to form said at least one gate electrode;
 - c. coating the structure thus formed with a photoresist layer (306);
 - d. exposing said photoresist layer (306) by high resolution means to form at least one group of emitting cells, the or each said group being located in an area of overlap between one said cathode electrode and one said gate electrode;
 - e. etching sequentially said third conducting layer (304), said insulating layer (304) and said second conducting layer (303) to expose said field emitting layer (302) in said cells; and
 - f. removing remaining areas of said photoresist layer (306).
2. A method according to claim 1, wherein said cathode is a cathode array, said cathode electrode and said gate electrode comprise respectively cathode addressing tracks and gate addressing tracks, which tracks are

arranged in addressable rows and columns, and step d. includes forming a pattern of said groups of emitting cells.

3. A method according to claim 2, wherein at least one of or all of said cathode addressing tracks address(es) a plurality of rows or columns of cells.

a 4. A method according to claim 2 ~~or 3~~, wherein said steps of exposing and etching include the formation of fiducial marks (432) on the cathode array, to facilitate the subsequent alignment of the array with an anode or other component after manufacture of the array.

a 5. A method according to ^{claim 1} ~~any of the preceding claims~~, comprising the step of forming at least one of said conducting layers (301, 303, 305) by application of a liquid bright metal or by electroless plating.

a 6. A method according to ^{claim 1} ~~any of the preceding claims~~, comprising the step of forming at least one of said conducting layers (301, 303, 305) by a means other than vacuum evaporation or sputtering.

a 20 7. A method according to ^{claim 1} ~~any of the preceding claims~~, wherein said field emitting layer (302) comprises a layer of broad area field emitter material.

a 8. A method according to ^{claim 1} ~~any of the preceding claims~~, comprising the further steps of depositing sequentially a second insulating layer (606) and fourth conducting layer (607) onto the cathode after completion of steps a. to f., to form a focus grid.

a 9. A field electron emission cathode which has been manufactured by a method according to ^{claim 1} ~~any of the preceding claims~~.

AD 10. A field emission device comprising an anode having electroluminescent phosphors (613) and a cathode according to ~~claim 9~~, wherein the cathode is a cathode array in accordance with claim 2 and is arranged to bombard said
5 ~~phosphors (613)~~.

11. A field emission device according to claim 10, wherein said phosphors (812) are arranged in groups of red, green and blue to form a colour display.

10 12. A field emission device according to claim 11, including anode driving means (804, 805, 806) for energising said red, green and blue groups in turn.

a 13. A field emission device according to claim 10, ~~11 or 12~~, further comprising an electrode (813) of interdigitate or mesh form which is
15 interposed between said phosphors (812) and is arranged to be driven at a potential less than that at which said phosphors (812) are driven, thereby to form potential wells around the phosphors in order to attract electrons (816) towards said phosphors (812) and compensate for any misalignment between cathode and anode.

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a 14. A field emission device according to ^{claim 9} ~~any of claims 9 to 13~~, wherein said cathode is provided with a further control grid over said gate electrode, and a driving means for so driving said control grid as to retard electrons emitted by the cathode.

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15. A field emission device according to claim 14, further comprising means for providing a magnetic field normal to the emitter surface.

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Year	1990	1991	1992	1993	1994	1995	1996	1997	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035	2036	2037	2038	2039	2040	2041	2042	2043	2044	2045	2046	2047	2048	2049	2050	2051	2052	2053	2054	2055	2056	2057	2058	2059	2060	2061	2062	2063	2064	2065	2066	2067	2068	2069	2070	2071	2072	2073	2074	2075	2076	2077	2078	2079	2080	2081	2082	2083	2084	2085	2086	2087	2088	2089	2090	2091	2092	2093	2094	2095	2096	2097	2098	2099	2100
1990	1991	1992	1993	1994	1995	1996	1997	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034	2035	2036	2037	2038	2039	2040	2041	2042	2043	2044	2045	2046	2047	2048	2049	2050	2051	2052	2053	2054	2055	2056	2057	2058	2059	2060	2061	2062	2063	2064	2065	2066	2067	2068	2069	2070	2071	2072	2073	2074	2075	2076	2077	2078	2079	2080	2081	2082	2083	2084	2085	2086	2087	2088	2089	2090	2091	2092	2093	2094	2095	2096	2097	2098	2099	2100	